	<p>SI1903DL-T1-GE3</p>
	<p>Hersteller-Teilenummer: SI1903DL-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET 2P-CH 20V 0.41A SC70-6</p> <p>Datenblätter:  SI1903DL-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 15002 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI1903DL-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET 2P-CH 20V 0.41A SC70-6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	15002 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	270mW
Verpackung / Gehäuse	6-TSSOP, SC-88, SOT-363
Supplier Device-Gehäuse	SC-70-6 (SOT-363)
Typ FET	2 P-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	410mA
Rds On (Max) @ Id, Vgs	995 mOhm @ 410mA, 4.5V
VGS (th) (Max) @ Id	1.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	1.8nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)



















































SI1903DL-T1-GE3 ist neu im Original. Suche SI1903DL-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1903DL-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI1903DL-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI1903DL-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 20V 0.41A SC70-6</p>	 <p>SI1905BDH-T1-GE3 V SI1905BDH-T1-GE3 V</p>	 <p>SI1904EDH-T1 SI SI1904EDH-T1 SI</p>	 <p>SI1903DL VISHAY SI1903DL VISHAY</p>
 <p>SI1905BDH-T1-E3 Vishay / Siliconix MOSFET 2P-CH 8V 0.63A SC70-6</p>	 <p>SI1905BDH-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 8V 0.63A SC70-6</p>	 <p>SI1903DL-T1-E3 Vishay / Siliconix MOSFET 2P-CH 20V 0.41A SC70-6</p>	 <p>SI1903DL-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 20V 0.41A SC70-6</p>

heiße Teile

Mehr

- | | | | | |
|---|--|--|--|--|
|  SI1867DL-T1-E3 |  SI1867DL-T1-E3 |  SI1867DL-T1-GE3 |  SI1867DL-T1-GE3 |  SI1900DL-T1 |
|  SI1900DL-T1-E3 |  SI1900DL-T1-E3 |  SI1900DL-T1-GE3 |  SI1900DL-T1-GE3 |  SI1901DL-T1 |
|  SI1901DL-T1-E3 |  SI1902CDL-T1-GE3 |  SI1902CDL-T1-GE3 |  SI1902DL |  SI1902DL-T1 |
|  SI1902DL-T1-E1 |  SI1902DL-T1-E3 |  SI1902DL-T1-E3 |  SI1902DL-T1-GE3 |  SI1902DL-T1-GE3 |
|  SI1903DL |  SI1903DL-T1 |  SI1903DL-T1-E3 |  SI1903DL-T1-E3 |  SI1903DL-T1-GE3 |
|  SI1904EDH-T1 |  SI1904EDH-T1-GE3 |  SI1905BDH-T1-E3 |  SI1905BDH-T1-E3 |  SI1905BDH-T1-GE3 |
|  SI1905BDH-T1-E3 |  SI1905DL |  SI1905DL-T1 |  SI1905DL-T1-E3 |  SI1905DL-T1-E3 |
|  SI1905DL-T1-GE3 |  SI1906DL-T1 |  SI1912EDH |  SI1912EDH-T1 |  SI1912EDH-T1-E3 |
|  SI1912EDH-T1-E3 |  SI1912EDH-T1-GE3 |  SI1913DH-T1-E3 |  SI1913DH-T1-E3 |  SI1913DH-T1-GE3 |
|  SI1913EDH-T1 |  SI1913EDH-T1-E3 |  SI1913EDH-T1-E3 |  SI1913EDH-T1-GE3 |  SI1917EDH-T1 |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited